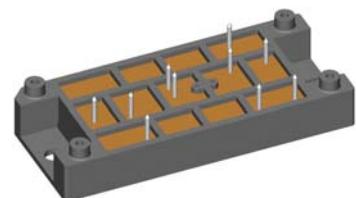
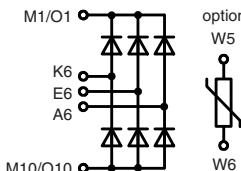


# Three Phase Rectifier Bridge

$I_{dAVM} = 121 / 157 \text{ A}$   
 $V_{RRM} = 1200-1600 \text{ V}$

$V_{RRM}$	Type	$V_{RRM}$	Type
V	V	V	V
1200	VUO 120-12 NO1	1600	VUO 120-16 NO1
1200	VUO 155-12 NO1	1600	VUO 155-16 NO1



pin configuration see outlines

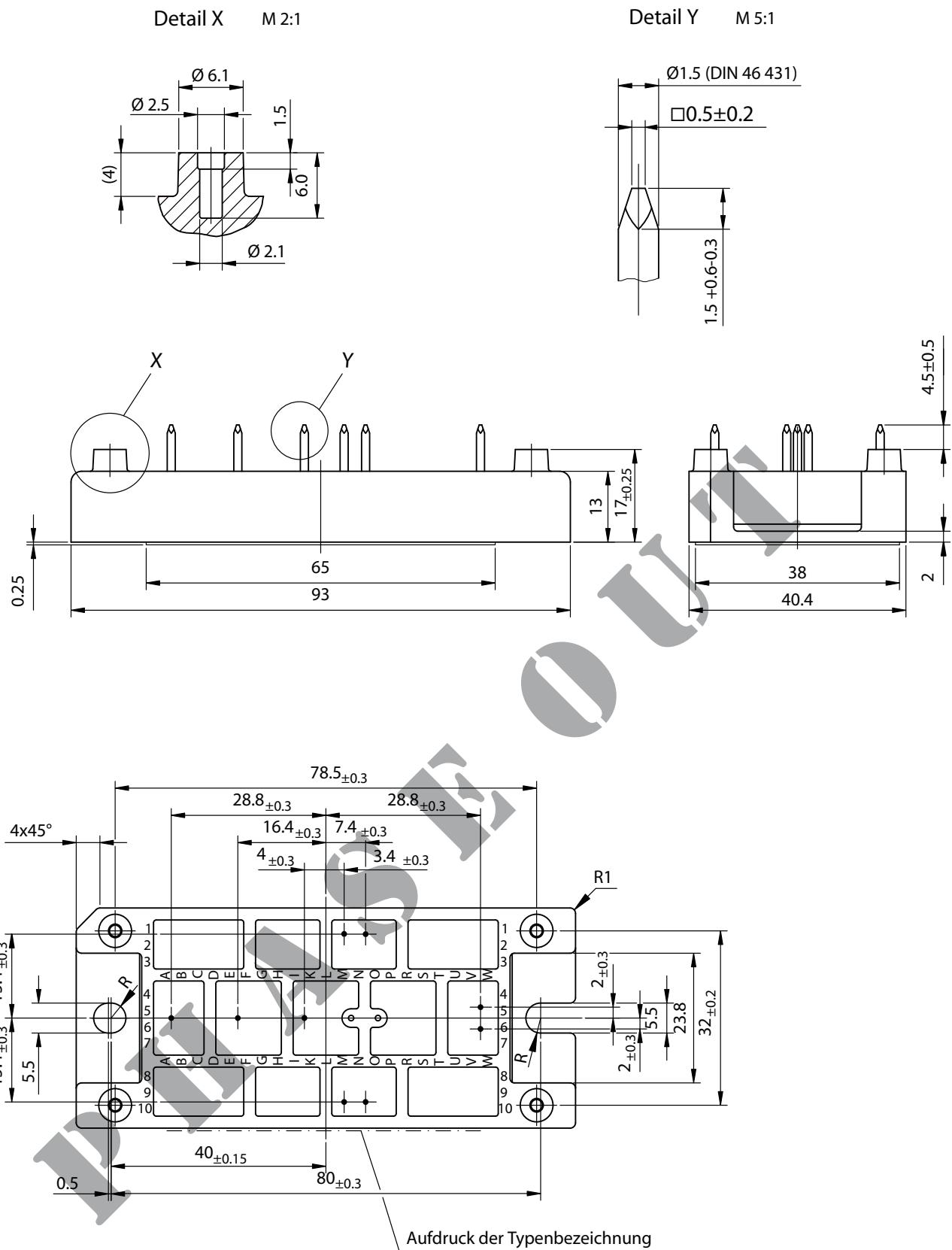
Symbol	Conditions	Maximum Ratings		Features
		VUO 120	VUO155	
$V_{RRM}$		1200/1600	1200/1600	V
$I_{dAVM}$	$T_C = 75^\circ\text{C}$ , sinusoidal 120°	121	157	A
$I_{FSM}$	$T_{VJ} = 45^\circ\text{C}$ , $T_{VJ} = 150^\circ\text{C}$ , $t = 10 \text{ ms}$ , $V_R = 0 \text{ V}$	650	850	A
	$t = 10 \text{ ms}$ , $V_R = 0 \text{ V}$	580	760	A
$I^2t$	$T_{VJ} = 45^\circ\text{C}$ , $T_{VJ} = 150^\circ\text{C}$ , $t = 10 \text{ ms}$ , $V_R = 0 \text{ V}$	2110	3610	A
	$t = 10 \text{ ms}$ , $V_R = 0 \text{ V}$	1680	2880	A
$P_{tot}$	$T_C = 25^\circ\text{C}$ per diode	150	190	W
$T_{VJ}$		-40...+150		$^\circ\text{C}$
$T_{VJM}$		150		$^\circ\text{C}$
$T_{stg}$		-40...+125		$^\circ\text{C}$
$V_{ISOL}$	50/60 Hz $I_{ISOL} \leq 1 \text{ mA}$	3000 3600	V~ V~	
$M_d$	Mounting torque (M5) (10-32 unf)	2-2.5 18-22	Nm lb.in.	
$d_s$	Creep distance on surface	12.7		mm
$d_A$	Strike distance in air	9.4		mm
$a$	Maximum allowable acceleration	50		$\text{m/s}^2$
Weight	typ.	80		g

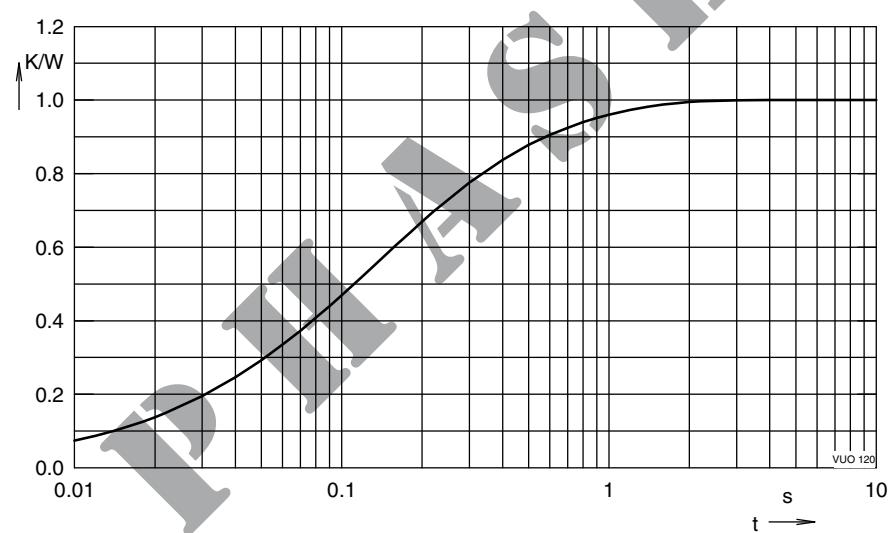
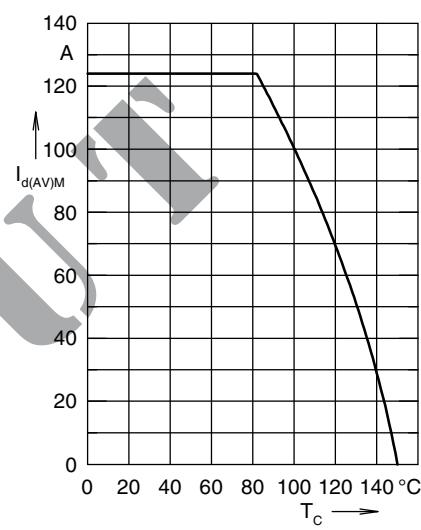
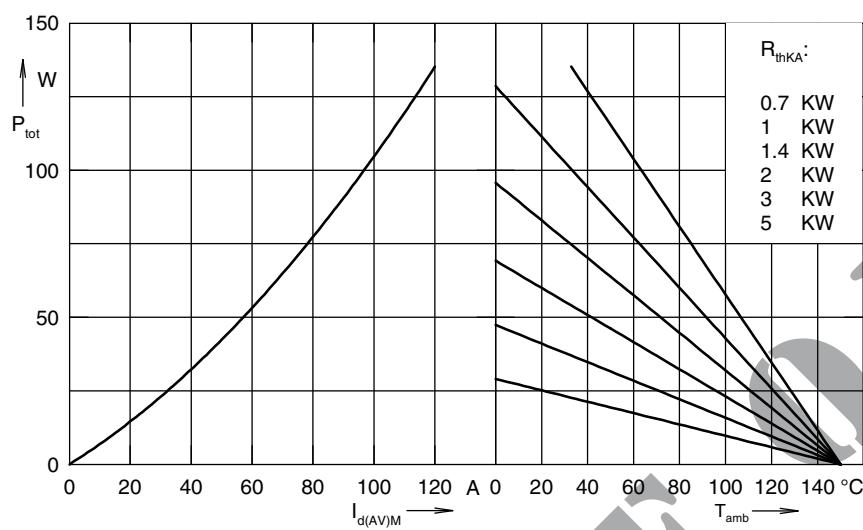
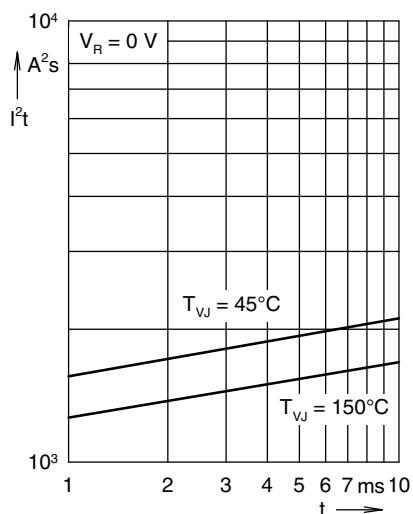
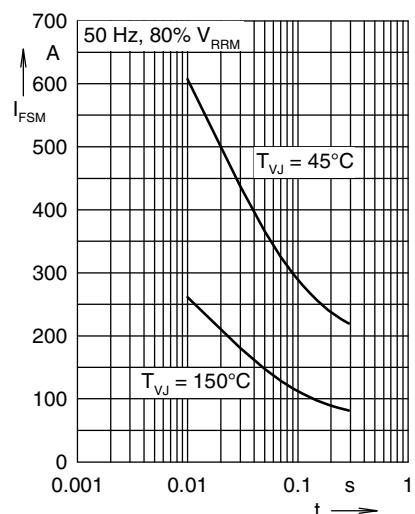
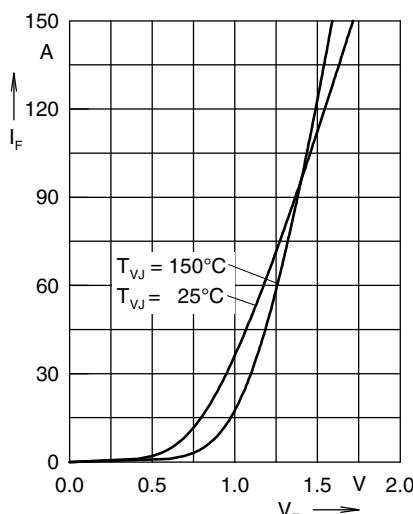
Symbol	Conditions	Characteristic Values		
		( $T_{VJ} = 25^\circ\text{C}$ , unless otherwise specified)	min.	typ.
$I_R$	$V_R = V_{RRM}$ , $V_R = V_{RRM}$ ,	$T_{VJ} = 25^\circ\text{C}$	0.3	mA
		$T_{VJ} = 150^\circ\text{C}$	5	mA
$V_F$	$I_F = 150 \text{ A}$ ,	$T_{VJ} = 25^\circ\text{C}$	VUO 120	1.59
			VUO 155	1.49
$V_{FO}$	For power-loss calculations only	VUO 120	0.80	V
		VUO 155	0.75	V
$r_T$	$T_{VJ} = 150^\circ\text{C}$	VUO 120	6.1	$\text{m}\Omega$
		VUO 155	4.6	$\text{m}\Omega$
$R_{thJC}$	per diode	VUO 120	1.0	K/W
		VUO 155	0.8	K/W
$R_{thJH}$		VUO 120	1.3	K/W
		VUO 155	1.1	K/W
$R_{25}$ (option)	Siemens S 891/2,2/+9		2.2	k $\Omega$

Type Recommended replacement

VUO120-12NO1	VUO120-12NO2T
VUO120-16NO1	VUO120-16NO2T
VUO155-12NO1	VUO120-12NO2T
VUO155-16NO1	VUO120-16NO2T

Dimensions in mm (1 mm = 0.0394")





Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.003521	0.01
2	0.1479	0.05
3	0.5599	0.14
4	0.2887	0.5

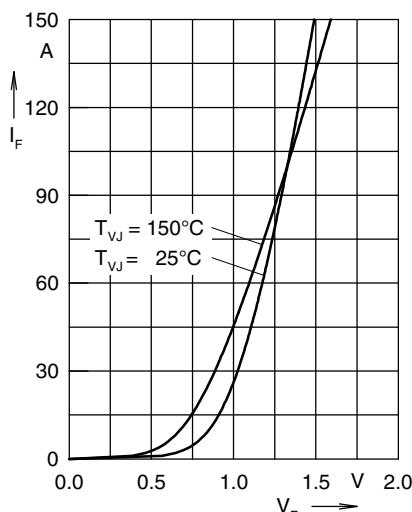


Fig. 1 Forward current versus voltage drop per diode

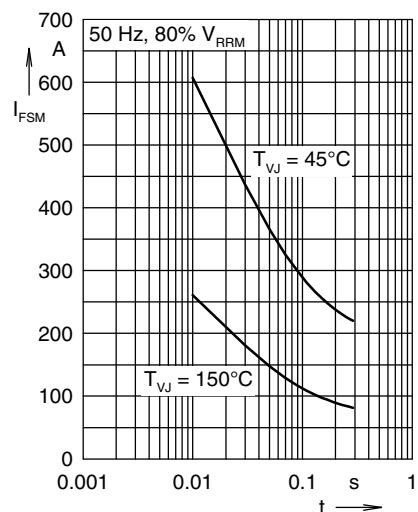


Fig. 2 Surge overload current

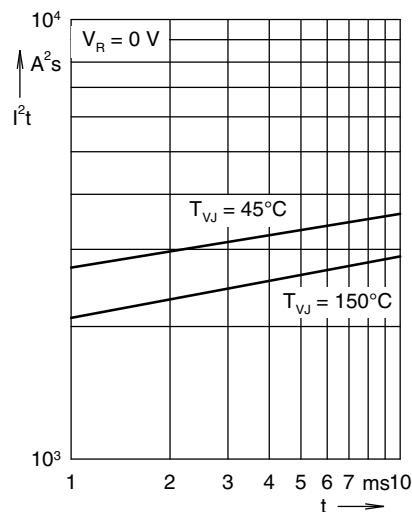


Fig. 3  $I^2t$  versus time per diode

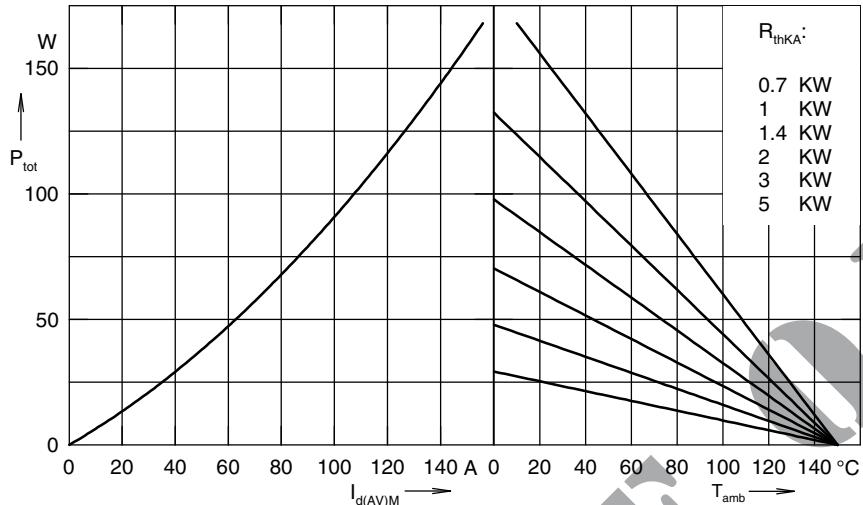


Fig. 4 Power dissipation versus direct output current and ambient temperature, sine 120°

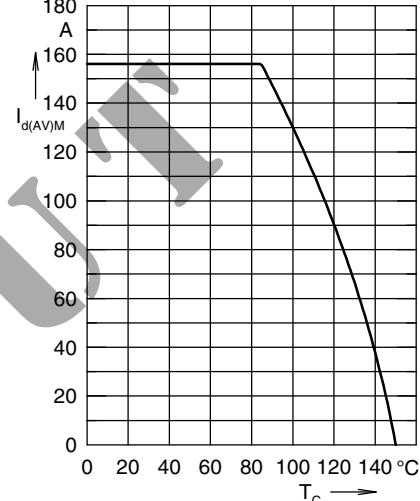


Fig. 5 Max. forward current versus case temperature

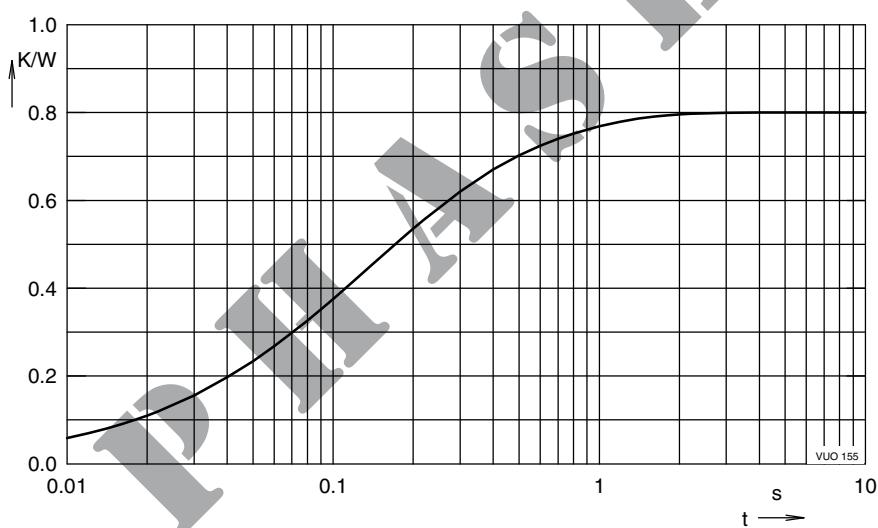


Fig. 6 Transient thermal impedance junction to case

Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.002817	0.01
2	0.1183	0.05
3	0.4479	0.14
4	0.231	0.5